

BLL6H1214-500; BLL6H1214LS-500

LDMOS L-band radar power transistor

Rev. 4 — 1 September 2015

AMPLEON

Product data sheet

1. Product profile

1.1 General description

500 W LDMOS power transistor intended for L-band radar applications in the 1.2 GHz to 1.4 GHz range.

Table 1. Test information

Typical RF performance at $T_{case} = 25\text{ °C}$; $t_p = 300\text{ }\mu\text{s}$; $\delta = 10\%$; $I_{Dq} = 150\text{ mA}$; in a class-AB production test circuit.

Test signal	f (GHz)	V _{DS} (V)	P _L (W)	G _p (dB)	η_D (%)	t _r (ns)	t _f (ns)
pulsed RF	1.2 to 1.4	50	500	17	50	20	6

1.2 Features and benefits

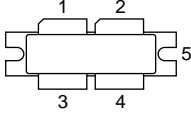
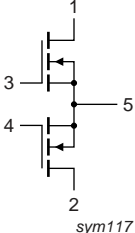
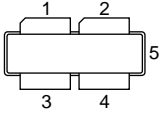
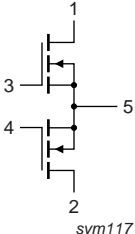
- Easy power control
- Integrated ESD protection
- High flexibility with respect to pulse formats
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (1.2 GHz to 1.4 GHz)
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding restriction of hazardous substances (RoHS)

1.3 Applications

- L-band power amplifiers for radar applications in the 1.2 GHz to 1.4 GHz frequency range

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
BLL6H1214-500 (SOT539A)			
1	drain1		 sym117
2	drain2		
3	gate1		
4	gate2		
5	source		
BLL6H1214LS-500 (SOT539B)			
1	drain1		 sym117
2	drain2		
3	gate1		
4	gate2		
5	source		

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLL6H1214-500	-	flanged balanced ceramic package; 2 mounting holes; 4 leads	SOT539A
BLL6H1214LS-500	-	earless flanged balanced ceramic package; 4 leads	SOT539B

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	100	V
V_{GS}	gate-source voltage		-0.5	+13	V
T_{stg}	storage temperature		-65	+150	°C
T_j	junction temperature		-	200	°C

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
BLL6H1214-500				
$Z_{th(j-c)}$	transient thermal impedance from junction to case	$T_{case} = 85\text{ °C}; P_L = 500\text{ W}$		
		$t_p = 100\text{ }\mu\text{s}; \delta = 10\text{ }\%$	0.07	K/W
		$t_p = 200\text{ }\mu\text{s}; \delta = 10\text{ }\%$	0.08	K/W
		$t_p = 300\text{ }\mu\text{s}; \delta = 10\text{ }\%$	0.1	K/W
		$t_p = 100\text{ }\mu\text{s}; \delta = 20\text{ }\%$	0.1	K/W
BLL6H1214LS-500				
$Z_{th(j-c)}$	transient thermal impedance from junction to case	$T_{case} = 85\text{ °C}; P_L = 500\text{ W}$		
		$t_p = 100\text{ }\mu\text{s}; \delta = 10\text{ }\%$	0.046	K/W
		$t_p = 200\text{ }\mu\text{s}; \delta = 10\text{ }\%$	0.059	K/W
		$t_p = 300\text{ }\mu\text{s}; \delta = 10\text{ }\%$	0.069	K/W
		$t_p = 100\text{ }\mu\text{s}; \delta = 20\text{ }\%$	0.064	K/W

6. Characteristics

Table 6. DC characteristics

$T_j = 25\text{ °C}$; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0\text{ V}; I_D = 2.7\text{ mA}$	100	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10\text{ V}; I_D = 270\text{ mA}$	1.3	1.8	2.2	V
I_{DSS}	drain leakage current	$V_{GS} = 0\text{ V}; V_{DS} = 50\text{ V}$	-	-	1.4	μA
I_{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75\text{ V}; V_{DS} = 10\text{ V}$	32	42	-	A
I_{GSS}	gate leakage current	$V_{GS} = 11\text{ V}; V_{DS} = 0\text{ V}$	-	-	140	nA
g_{fs}	forward transconductance	$V_{DS} = 10\text{ V}; I_D = 270\text{ mA}$	1.7	3	-	S
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75\text{ V}; I_D = 9.5\text{ A}$	-	100	164	$\text{m}\Omega$

Table 7. RF characteristics

Test signal: pulsed RF; $t_p = 300\text{ }\mu\text{s}; \delta = 10\text{ }\%$; RF performance at $V_{DS} = 50\text{ V}; I_{Dq} = 150\text{ mA}$; $T_{case} = 25\text{ °C}$; unless otherwise specified, in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
P_L	output power		500	-	-	W
V_{DS}	drain-source voltage	$P_L = 500\text{ W}$	-	-	50	V
G_p	power gain	$P_L = 500\text{ W}$	15	17	-	dB
RL_{in}	input return loss	$P_L = 500\text{ W}$	-	-10	-	dB
$P_{L(1dB)}$	output power at 1 dB gain compression		-	600	-	W
η_D	drain efficiency	$P_L = 500\text{ W}$	45	50	-	%

Table 7. RF characteristics ...continued

Test signal: pulsed RF; $t_p = 300 \mu\text{s}$; $\delta = 10 \%$; RF performance at $V_{DS} = 50 \text{ V}$; $I_{Dq} = 150 \text{ mA}$; $T_{case} = 25 \text{ }^\circ\text{C}$; unless otherwise specified, in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$P_{\text{droop(pulse)}}$	pulse droop power	$P_L = 500 \text{ W}$	-	0	0.3	dB
t_r	rise time	$P_L = 500 \text{ W}$	-	20	50	ns
t_f	fall time	$P_L = 500 \text{ W}$	-	6	50	ns

7. Test information

7.1 Ruggedness in class-AB operation

The BLL6H1214-500 and BLL6H1214LS-500 are capable of withstanding a load mismatch corresponding to $V_{\text{SWR}} = 10 : 1$ through all phases under the following conditions: $V_{DS} = 50 \text{ V}$; $I_{Dq} = 150 \text{ mA}$; $P_L = 500 \text{ W}$; $t_p = 300 \mu\text{s}$; $\delta = 10 \%$.

7.2 Impedance information

Table 8. Typical impedance

Typical values per section unless otherwise specified.

f (GHz)	Z_S (Ω)	Z_L (Ω)
1.2	$1.268 - j2.623$	$2.987 - j1.664$
1.3	$2.193 - j2.457$	$2.162 - j1.326$
1.4	$2.359 - j2.052$	$1.604 - j1.887$

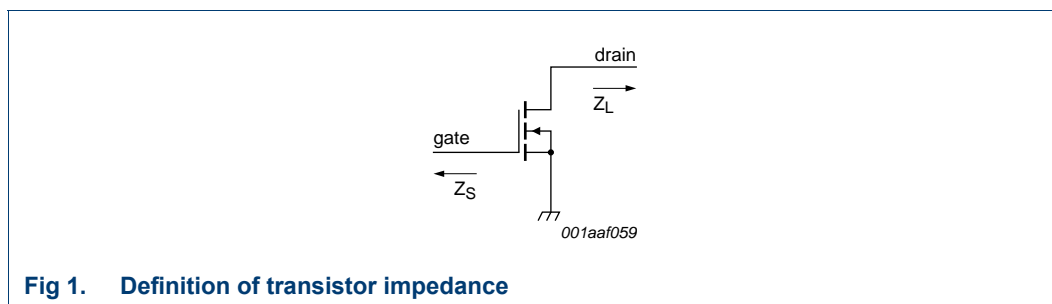


Fig 1. Definition of transistor impedance

7.3 Test circuit

Table 9. List of components

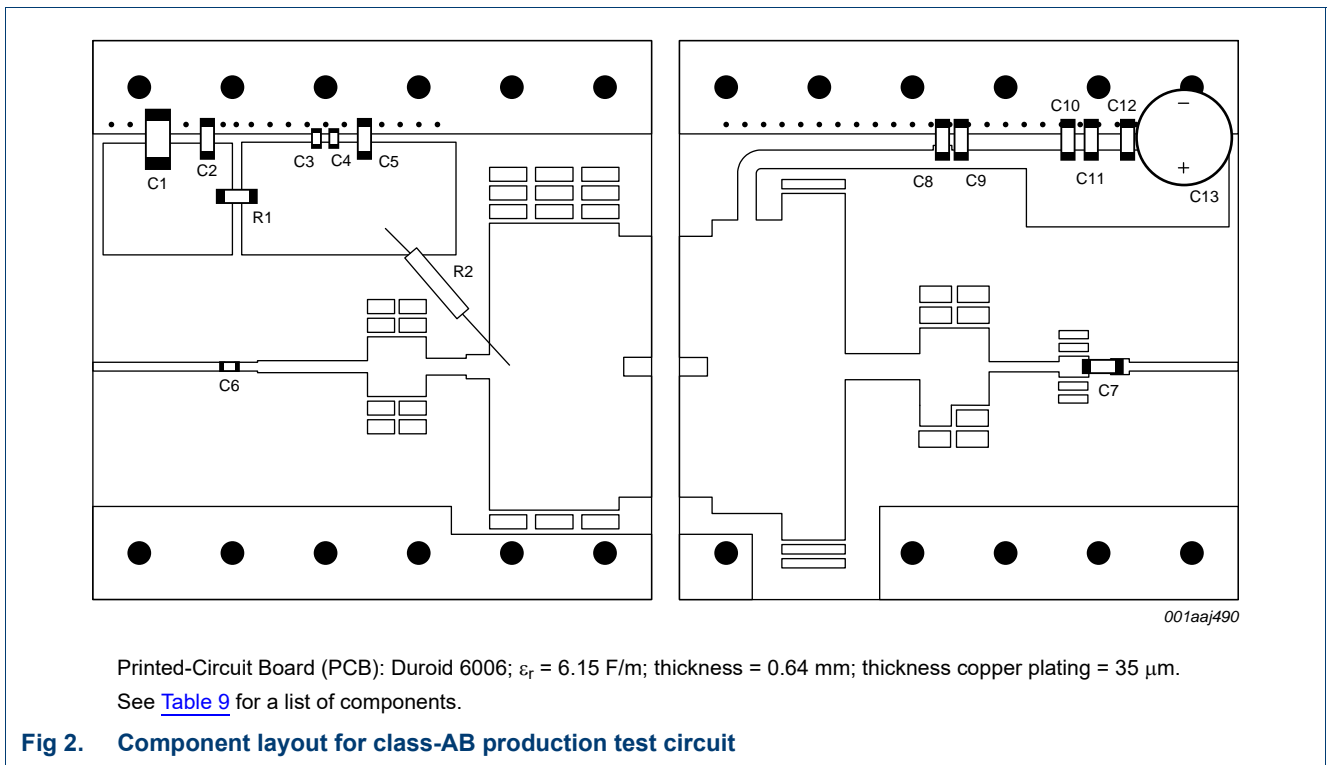
For test circuit see [Figure 2](#).

Component	Description	Value	Remarks
C1	multilayer ceramic chip capacitor	22 μF , 35 V	
C2	multilayer ceramic chip capacitor	51 pF	[1]
C3, C4	multilayer ceramic chip capacitor	100 pF	[1]
C5, C11, C12	multilayer ceramic chip capacitor	1 nf	[2]
C6	multilayer ceramic chip capacitor	47 pF	[1]
C7, C8, C10	multilayer ceramic chip capacitor	51 pF	[3]

Table 9. List of components ...continued
 For test circuit see [Figure 2](#).

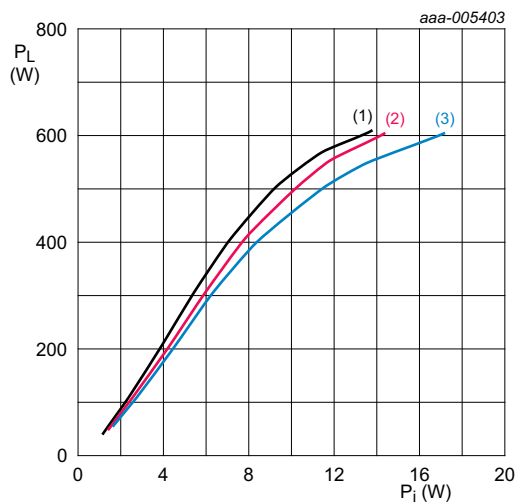
Component	Description	Value	Remarks
C9	multilayer ceramic chip capacitor	100 pF	[3]
C13	electrolytic capacitor	10 μF, 63 V	
R1	SMD resistor	56 Ω	0603
R2	metal film resistor	51 Ω	

- [1] American Technical Ceramics type 100A or capacitor of same quality.
- [2] American Technical Ceramics type 100B or capacitor of same quality.
- [3] American Technical Ceramics type 800B or capacitor of same quality.



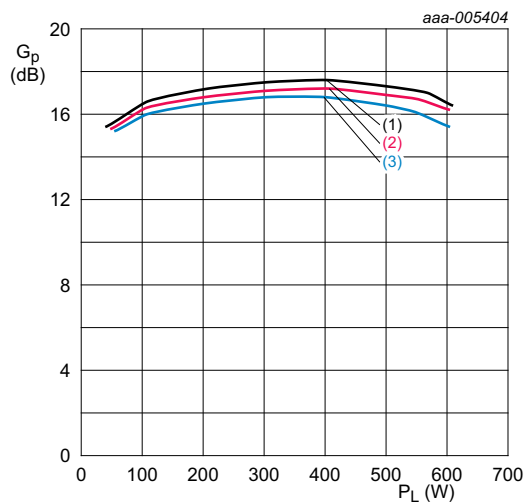
7.4 RF performance graphs

7.4.1 Performance curves measured with $\delta = 10\%$, $t_p = 300 \mu s$ and $T_h = 25^\circ C$



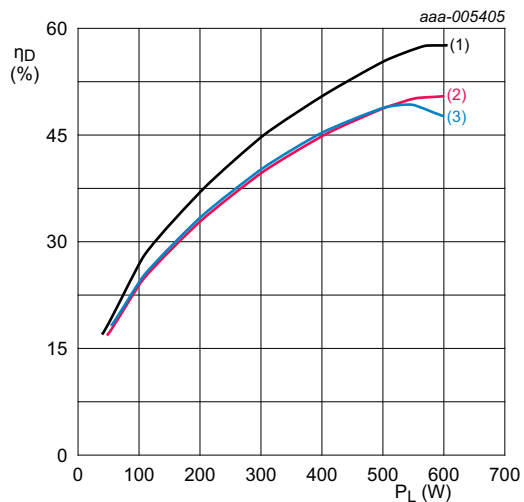
$V_{DS} = 50 V$; $I_{Dq} = 150 mA$.
 (1) $f = 1200 MHz$
 (2) $f = 1300 MHz$
 (3) $f = 1400 MHz$

Fig 3. Output power as a function of input power; typical values



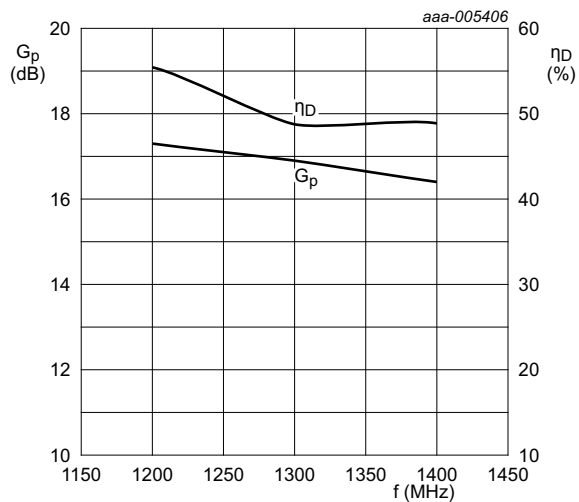
$V_{DS} = 50 V$; $I_{Dq} = 150 mA$.
 (1) $f = 1200 MHz$
 (2) $f = 1300 MHz$
 (3) $f = 1400 MHz$

Fig 4. Power gain as a function of output power; typical values



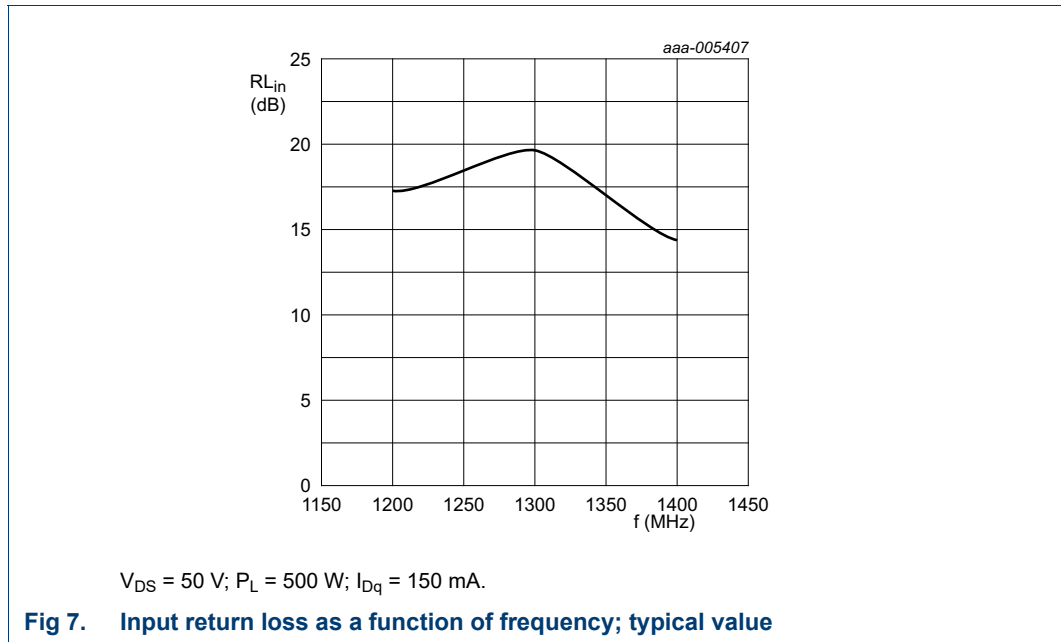
$V_{DS} = 50 V$; $I_{Dq} = 150 mA$.
 (1) $f = 1200 MHz$
 (2) $f = 1300 MHz$
 (3) $f = 1400 MHz$

Fig 5. Drain efficiency as a function of output power; typical values

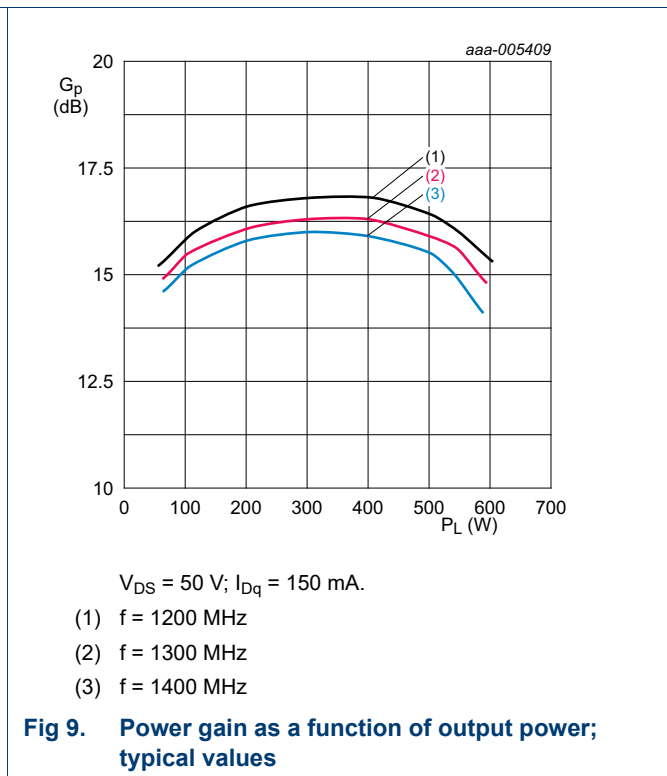
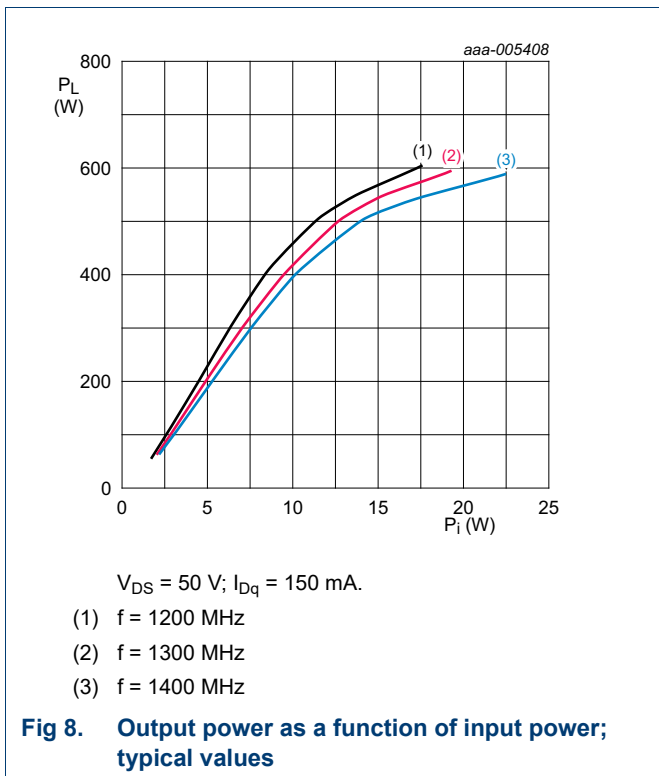


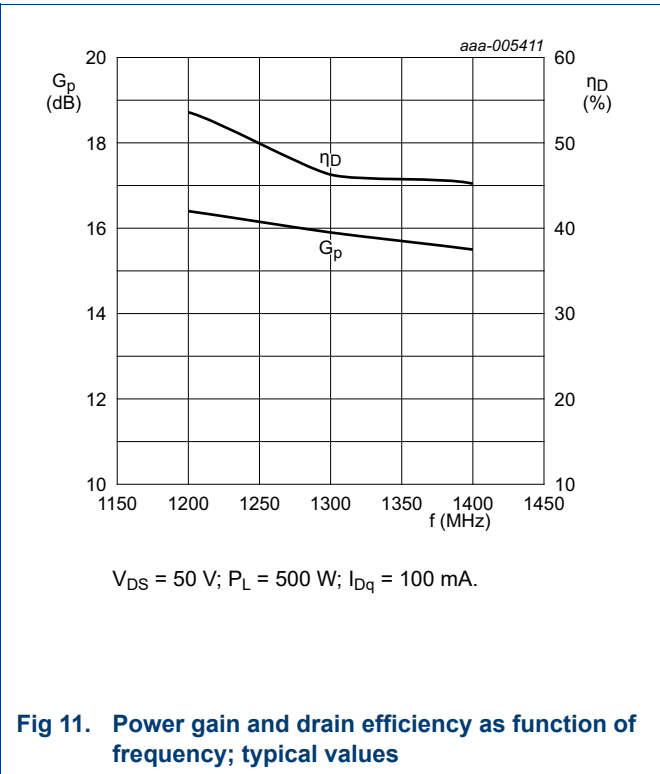
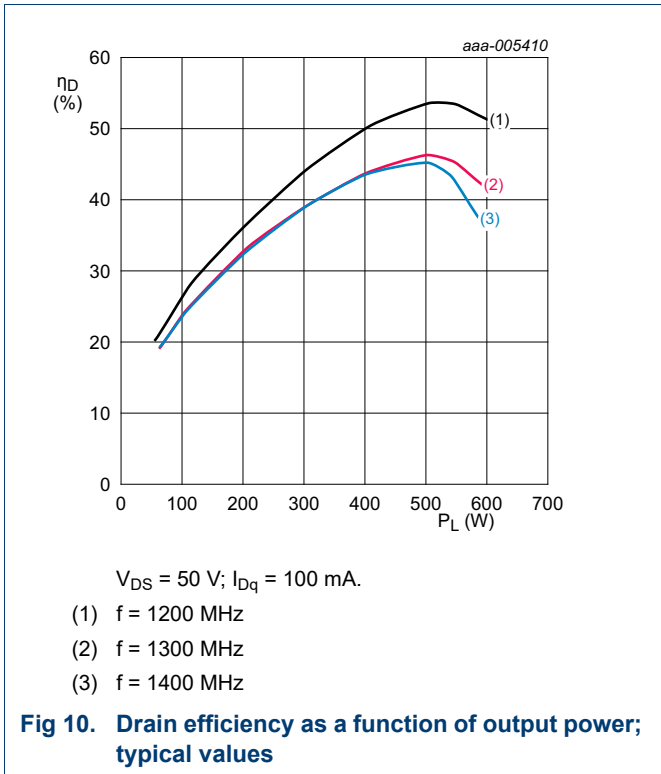
$V_{DS} = 50 V$; $P_L = 500 W$; $I_{Dq} = 150 mA$.

Fig 6. Power gain and drain efficiency as function of frequency; typical values

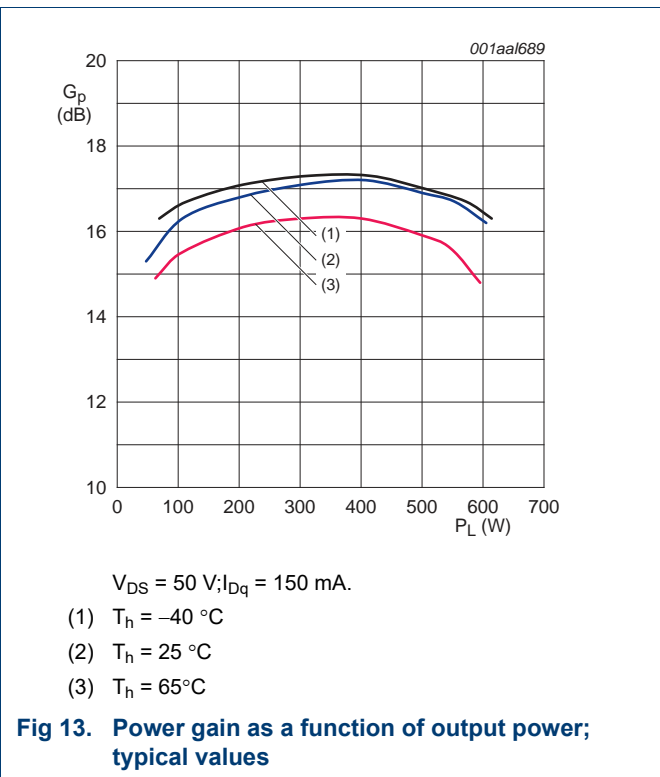
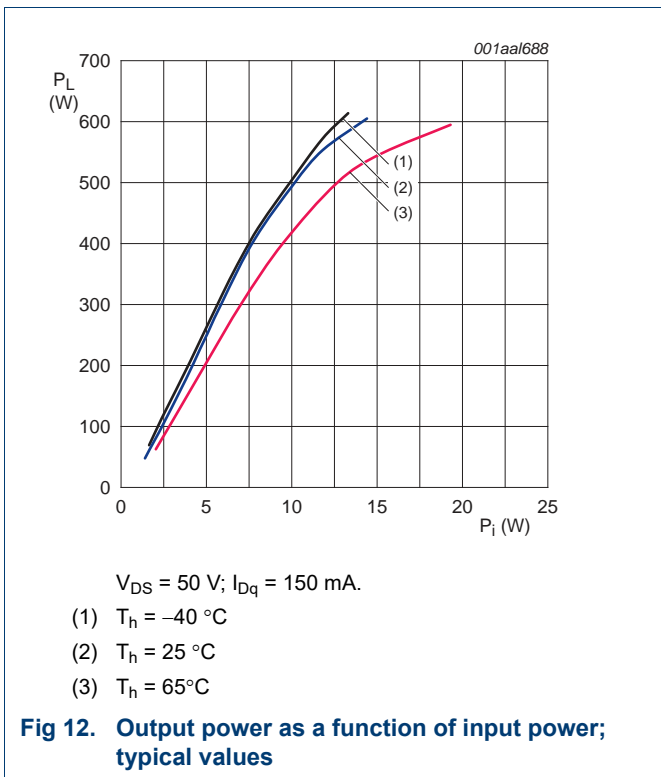


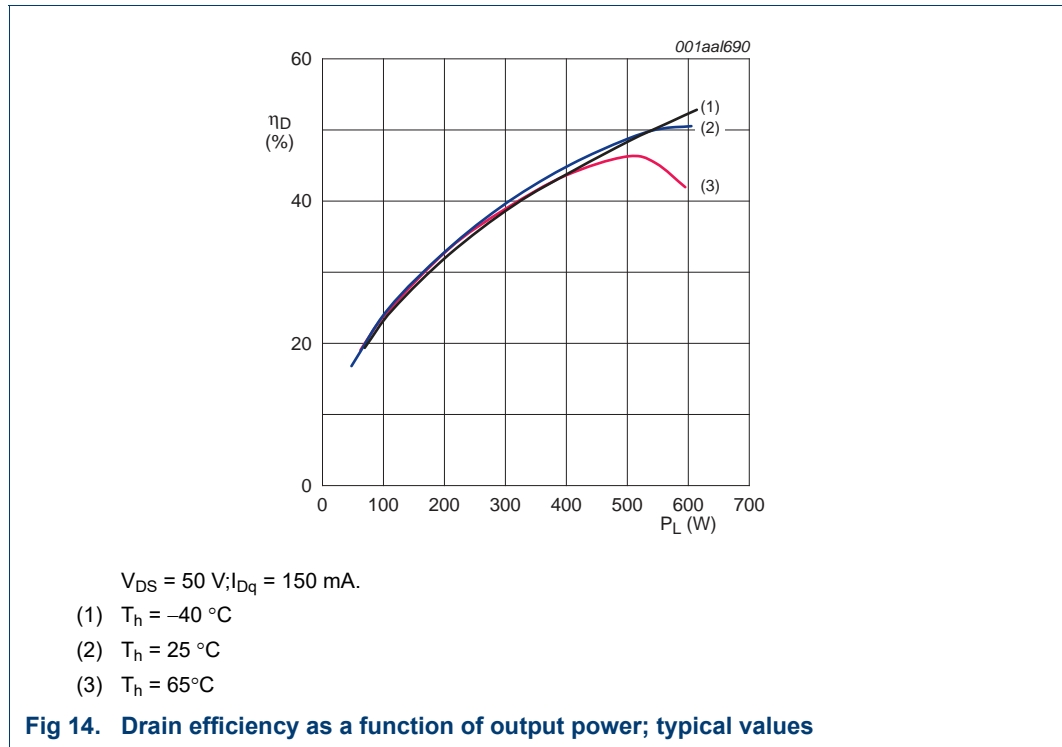
7.4.2 Performance curves measured with $\delta = 10 \%$, $t_p = 300 \mu\text{s}$ and $T_h = 65 \text{ }^\circ\text{C}$



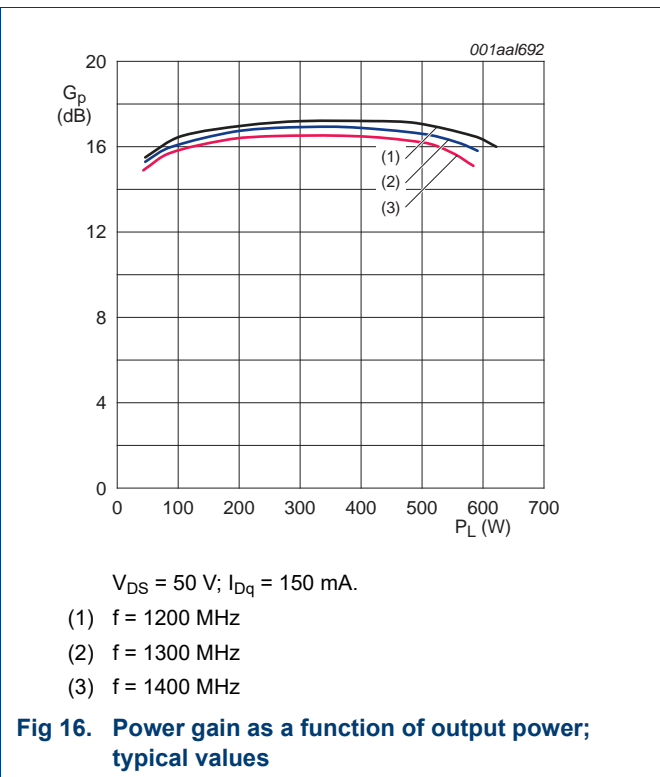
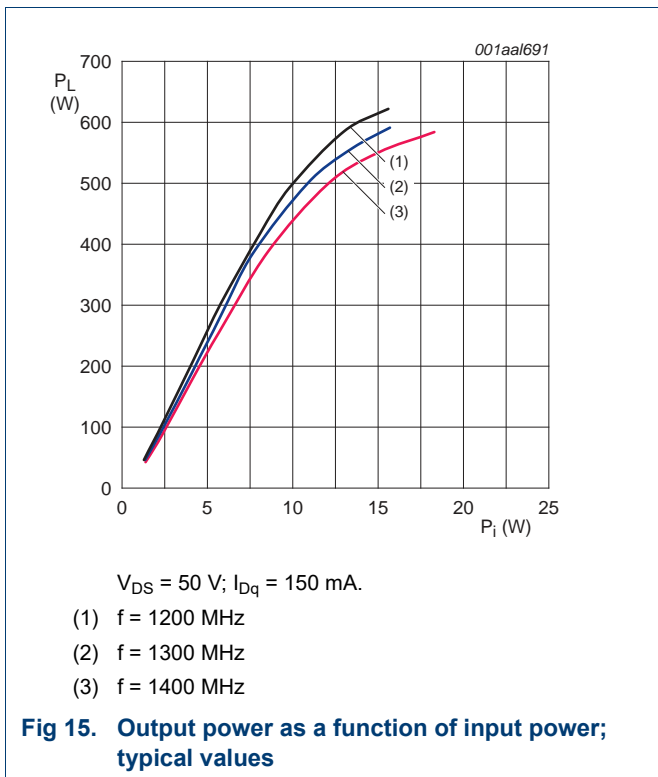


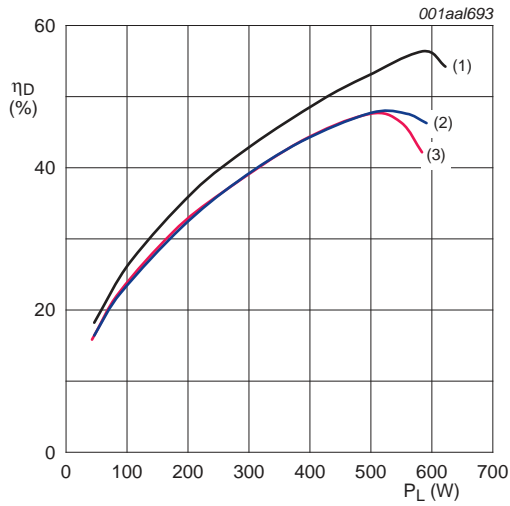
7.4.3 Performance curves measured with $\delta = 10 \%$, $t_p = 300 \mu\text{s}$ and $f = 1300 \text{ MHz}$





7.4.4 Performance curves measured with $\delta = 20 \%$, $t_p = 500 \mu\text{s}$ and $T_h = 25 \text{ }^\circ\text{C}$

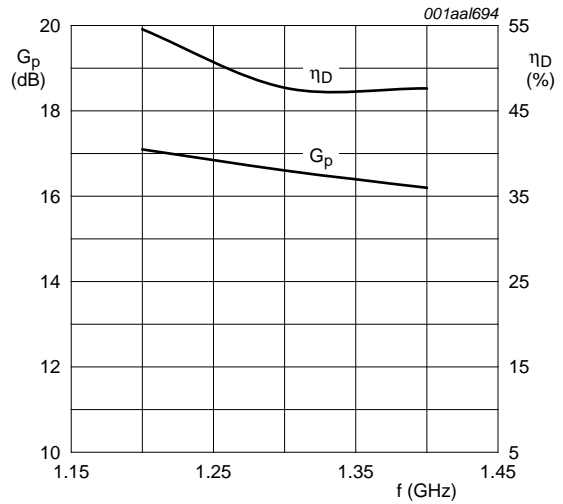




$V_{DS} = 50\text{ V}; I_{Dq} = 150\text{ mA}$.

- (1) $f = 1200\text{ MHz}$
- (2) $f = 1300\text{ MHz}$
- (3) $f = 1400\text{ MHz}$

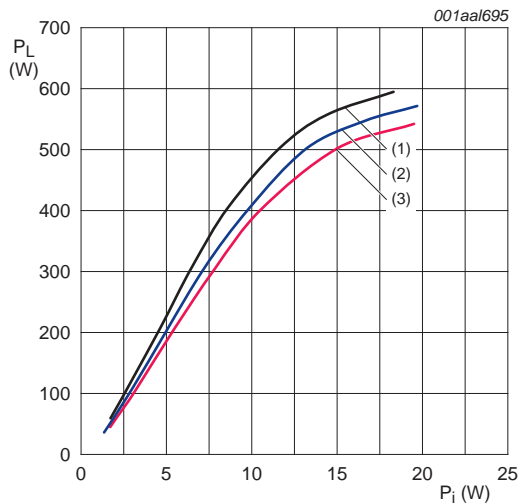
Fig 17. Drain efficiency as a function of output power; typical values



$V_{DS} = 50\text{ V}; I_{Dq} = 150\text{ mA}$.

Fig 18. Power gain and drain efficiency as function of frequency; typical values

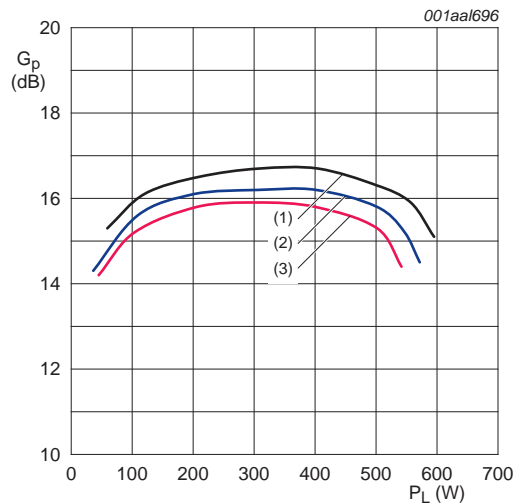
7.4.5 Performance curves measured with $\delta = 20\%$, $t_p = 500\ \mu\text{s}$ and $T_h = 65\text{ }^\circ\text{C}$



$V_{DS} = 50\text{ V}; I_{Dq} = 150\text{ mA}$.

- (1) $f = 1200\text{ MHz}$
- (2) $f = 1300\text{ MHz}$
- (3) $f = 1400\text{ MHz}$

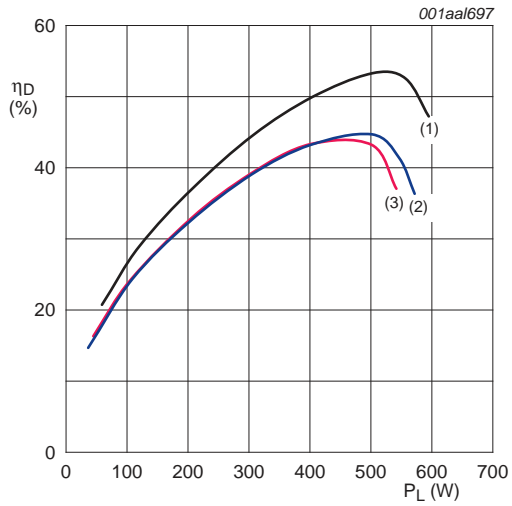
Fig 19. Output power as a function of input power; typical values



$V_{DS} = 50\text{ V}; I_{Dq} = 150\text{ mA}$.

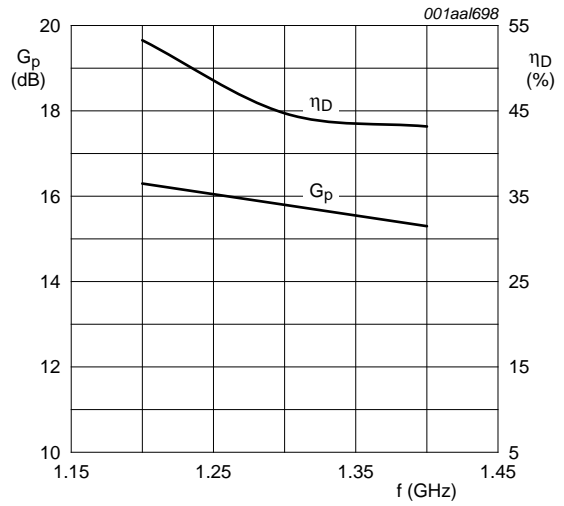
- (1) $f = 1200\text{ MHz}$
- (2) $f = 1300\text{ MHz}$
- (3) $f = 1400\text{ MHz}$

Fig 20. Power gain as a function of output power; typical values



$V_{DS} = 50\text{ V}; I_{Dq} = 150\text{ mA}.$
 (1) $f = 1200\text{ MHz}$
 (2) $f = 1300\text{ MHz}$
 (3) $f = 1400\text{ MHz}$

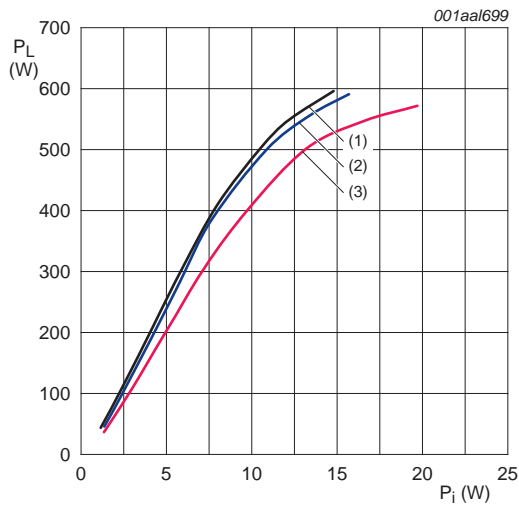
Fig 21. Drain efficiency as a function of output power; typical values



$V_{DS} = 50\text{ V}; I_{Dq} = 150\text{ mA}.$

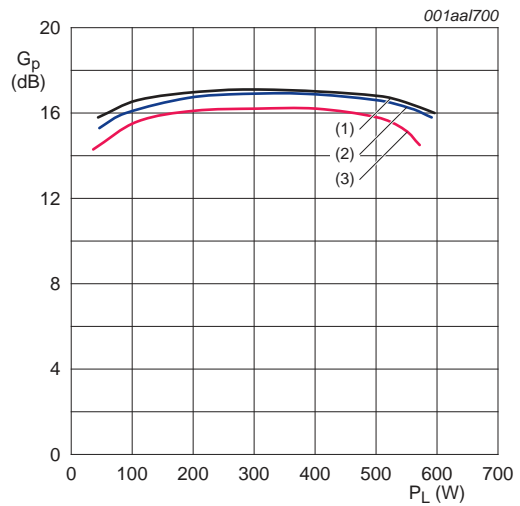
Fig 22. Power gain and drain efficiency as function of frequency; typical values

7.4.6 Performance curves measured with $\delta = 20\%$, $t_p = 500\ \mu\text{s}$ and $f = 1300\text{ MHz}$



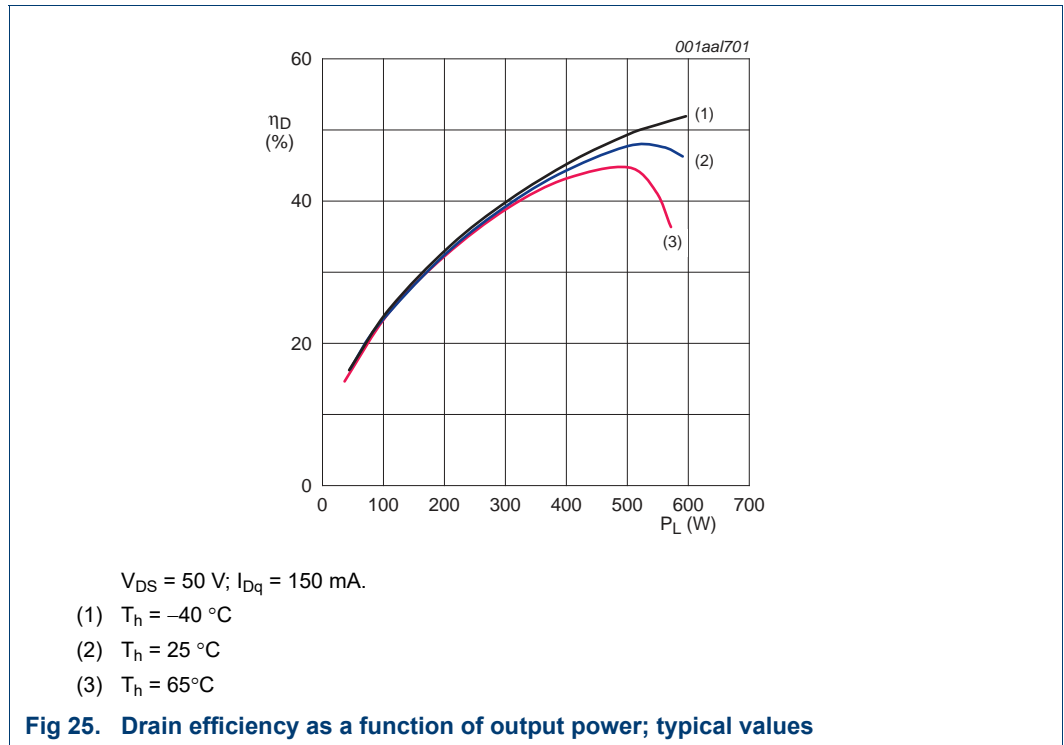
$V_{DS} = 50\text{ V}; I_{Dq} = 150\text{ mA}.$
 (1) $T_h = -40^\circ\text{C}$
 (2) $T_h = 25^\circ\text{C}$
 (3) $T_h = 65^\circ\text{C}$

Fig 23. Output power as a function of input power; typical values

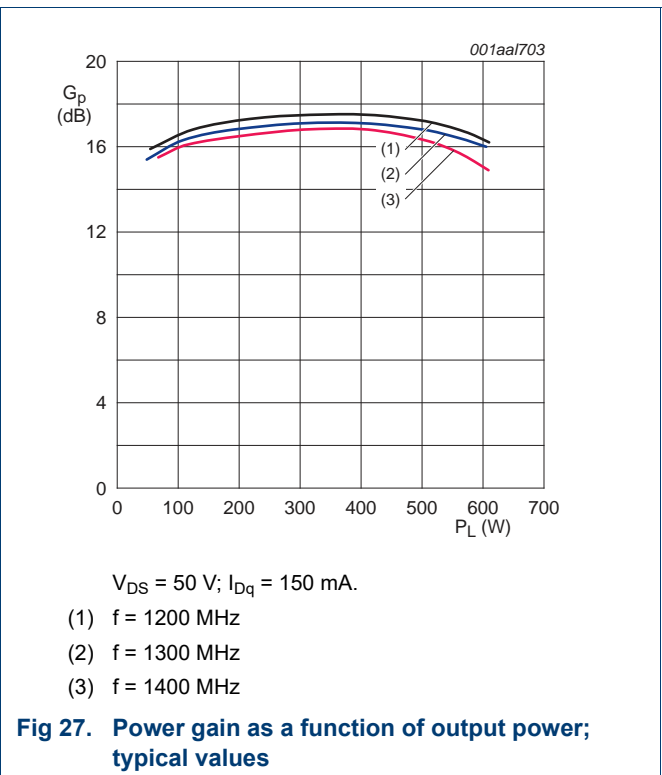
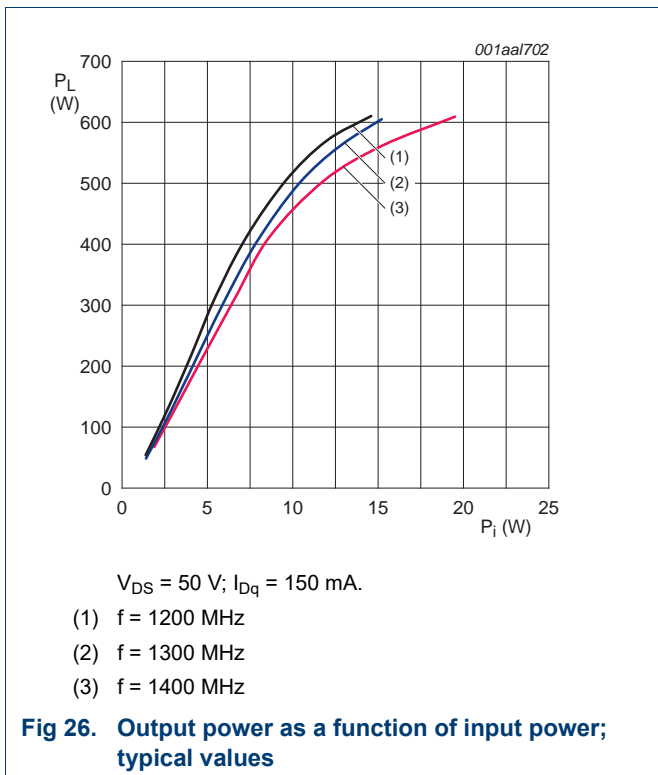


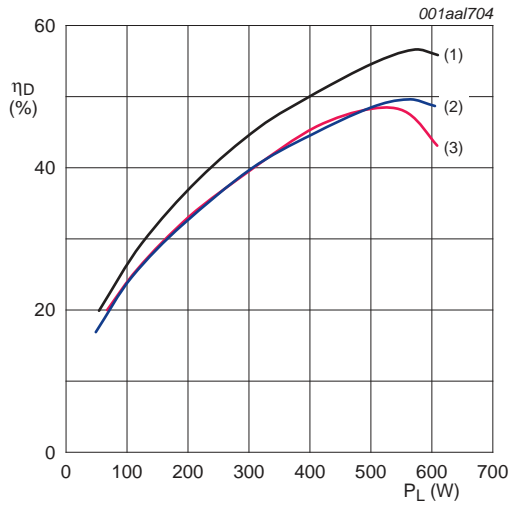
$V_{DS} = 50\text{ V}; I_{Dq} = 150\text{ mA}.$
 (1) $T_h = -40^\circ\text{C}$
 (2) $T_h = 25^\circ\text{C}$
 (3) $T_h = 65^\circ\text{C}$

Fig 24. Power gain as a function of output power; typical values



7.4.7 Performance curves measured with $\delta = 10 \%$, $t_p = 1 \text{ ms}$ and $T_h = 25 \text{ }^\circ\text{C}$

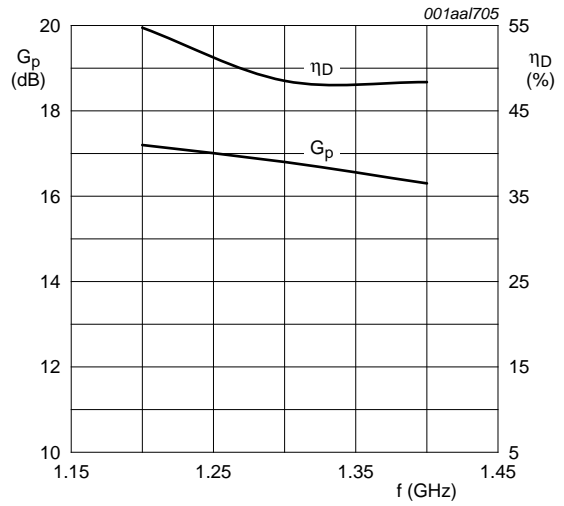




$V_{DS} = 50\text{ V}; I_{Dq} = 150\text{ mA}$.

- (1) $f = 1200\text{ MHz}$
- (2) $f = 1300\text{ MHz}$
- (3) $f = 1400\text{ MHz}$

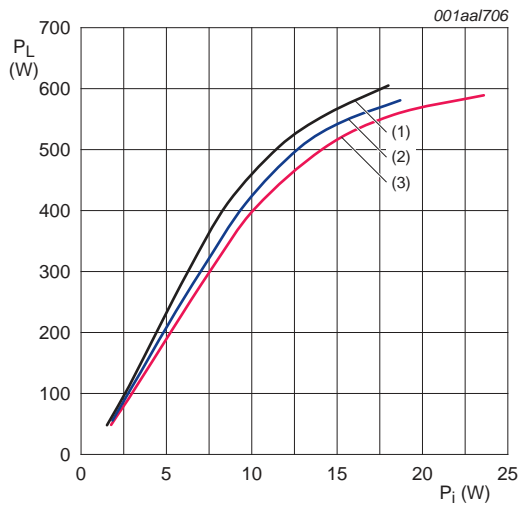
Fig 28. Drain efficiency as a function of output power; typical values



$V_{DS} = 50\text{ V}; I_{Dq} = 150\text{ mA}$.

Fig 29. Power gain and drain efficiency as function of frequency; typical values

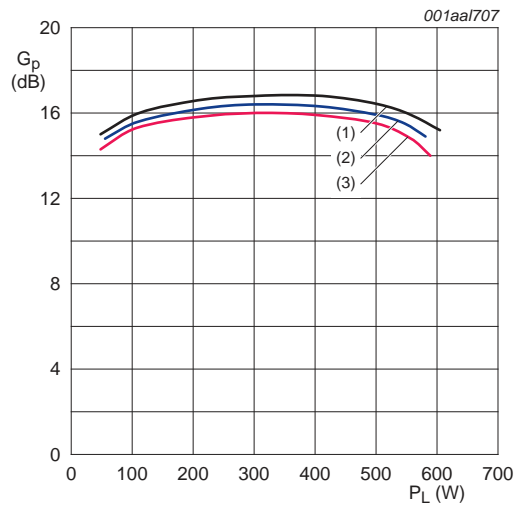
7.4.8 Performance curves measured with $\delta = 10\%$, $t_p = 1\text{ ms}$ and $T_h = 65\text{ }^\circ\text{C}$



$V_{DS} = 50\text{ V}; I_{Dq} = 150\text{ mA}$.

- (1) $f = 1200\text{ MHz}$
- (2) $f = 1300\text{ MHz}$
- (3) $f = 1400\text{ MHz}$

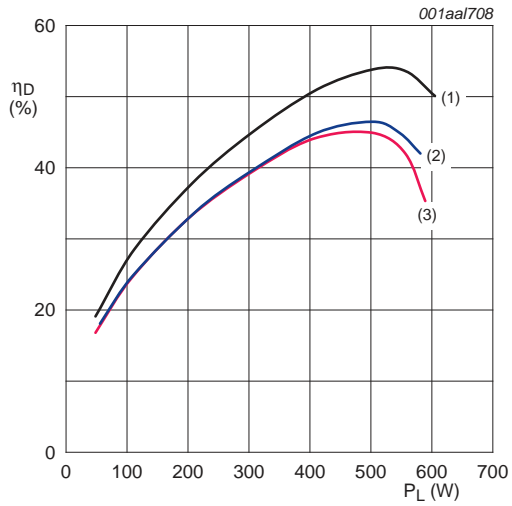
Fig 30. Output power as a function of input power; typical values



$V_{DS} = 50\text{ V}; I_{Dq} = 150\text{ mA}$.

- (1) $f = 1200\text{ MHz}$
- (2) $f = 1300\text{ MHz}$
- (3) $f = 1400\text{ MHz}$

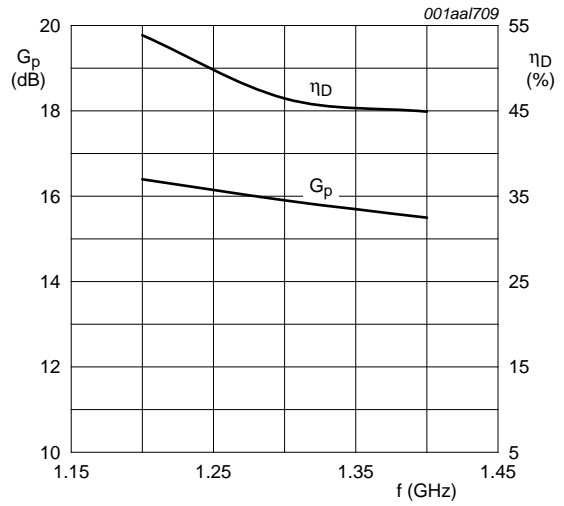
Fig 31. Power gain as a function of output power; typical values



$V_{DS} = 50 \text{ V}; I_{Dq} = 150 \text{ mA}$.

- (1) $f = 1200 \text{ MHz}$
- (2) $f = 1300 \text{ MHz}$
- (3) $f = 1400 \text{ MHz}$

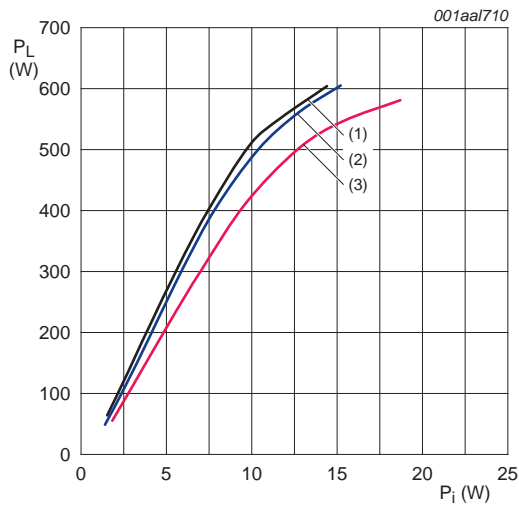
Fig 32. Drain efficiency as a function of output power; typical values



$V_{DS} = 50 \text{ V}; I_{Dq} = 150 \text{ mA}$.

Fig 33. Power gain and drain efficiency as function of frequency; typical values

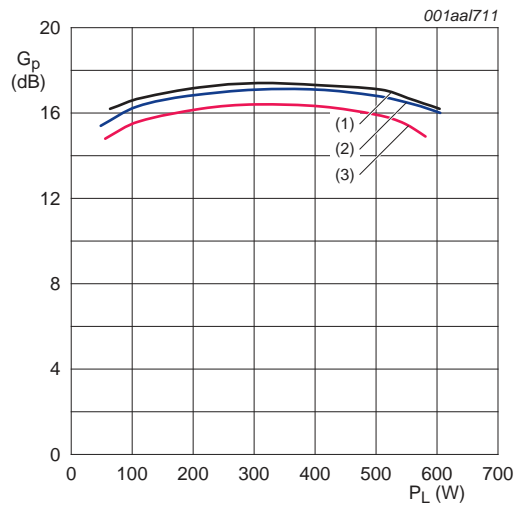
7.4.9 Performance curves measured with $\delta = 10 \%$, $t_p = 1 \text{ ms}$ and $f = 1300 \text{ MHz}$



$V_{DS} = 50 \text{ V}; I_{Dq} = 150 \text{ mA}$.

- (1) $T_h = -40 \text{ }^\circ\text{C}$
- (2) $T_h = 25 \text{ }^\circ\text{C}$
- (3) $T_h = 65 \text{ }^\circ\text{C}$

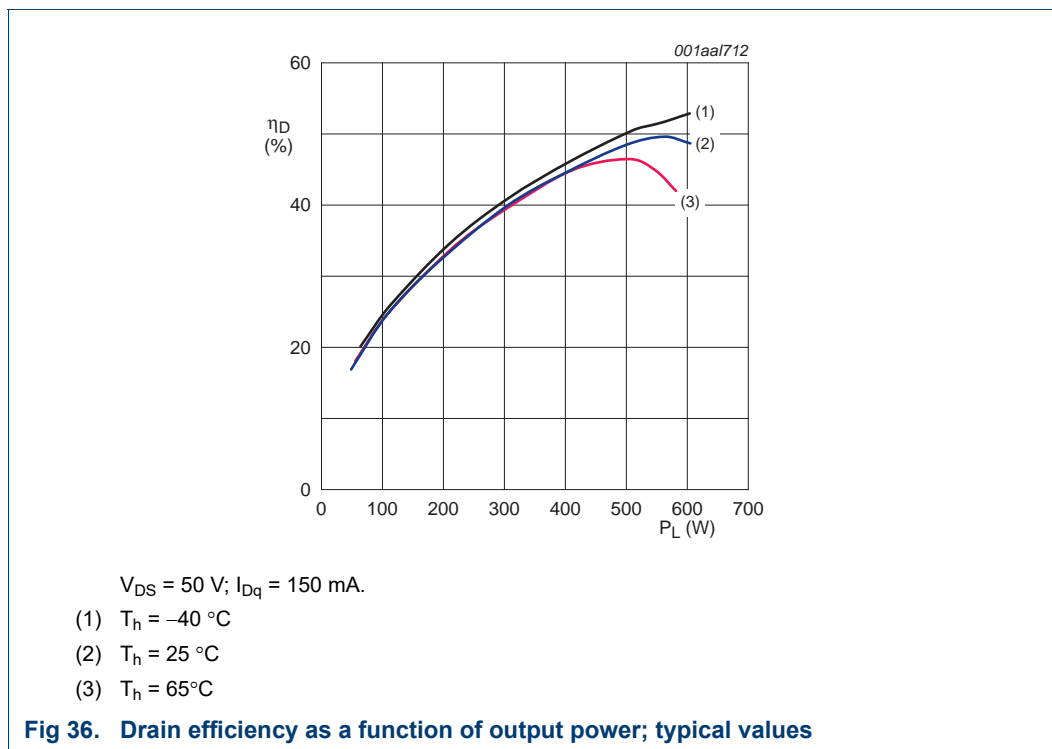
Fig 34. Output power as a function of input power; typical values



$V_{DS} = 50 \text{ V}; I_{Dq} = 150 \text{ mA}$.

- (1) $T_h = -40 \text{ }^\circ\text{C}$
- (2) $T_h = 25 \text{ }^\circ\text{C}$
- (3) $T_h = 65 \text{ }^\circ\text{C}$

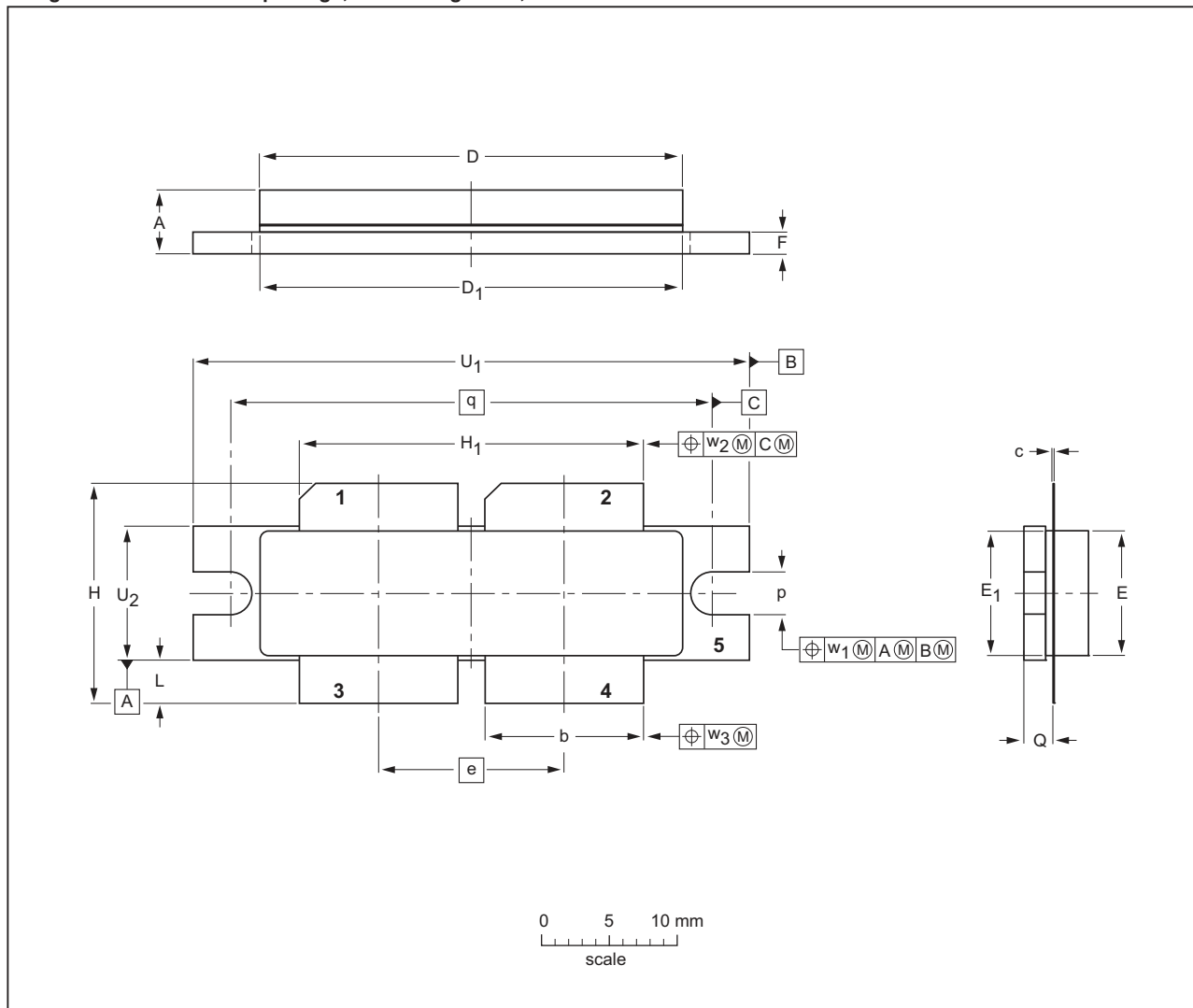
Fig 35. Power gain as a function of output power; typical values



8. Package outline

Flanged balanced ceramic package; 2 mounting holes; 4 leads

SOT539A



DIMENSIONS (millimetre dimensions are derived from the original inch dimensions)

UNIT	A	b	c	D	D ₁	e	E	E ₁	F	H	H ₁	L	p	Q	q	U ₁	U ₂	w ₁	w ₂	w ₃
mm	4.7 4.2	11.81 11.56	0.18 0.10	31.55 30.94	31.52 30.96	13.72	9.50 9.30	9.53 9.27	1.75 1.50	17.12 16.10	25.53 25.27	3.48 2.97	3.30 3.05	2.26 2.01	35.56	41.28 41.02	10.29 10.03	0.25	0.51	0.25
inches	0.185 0.165	0.465 0.455	0.007 0.004	1.242 1.218	1.241 1.219	0.540	0.374 0.366	0.375 0.365	0.069 0.059	0.674 0.634	1.005 0.995	0.137 0.117	0.130 0.120	0.089 0.079	1.400	1.625 1.615	0.405 0.395	0.010	0.020	0.010

Note

1. millimeter dimensions are derived from the original inch dimensions.
2. recommended screw pitch dimension of 1.52 inch (38.6 mm) based on M3 screw.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT539A						10-02-02 12-05-02

Fig 37. Package outline SOT539A

Earless flanged balanced ceramic package; 4 leads

SOT539B

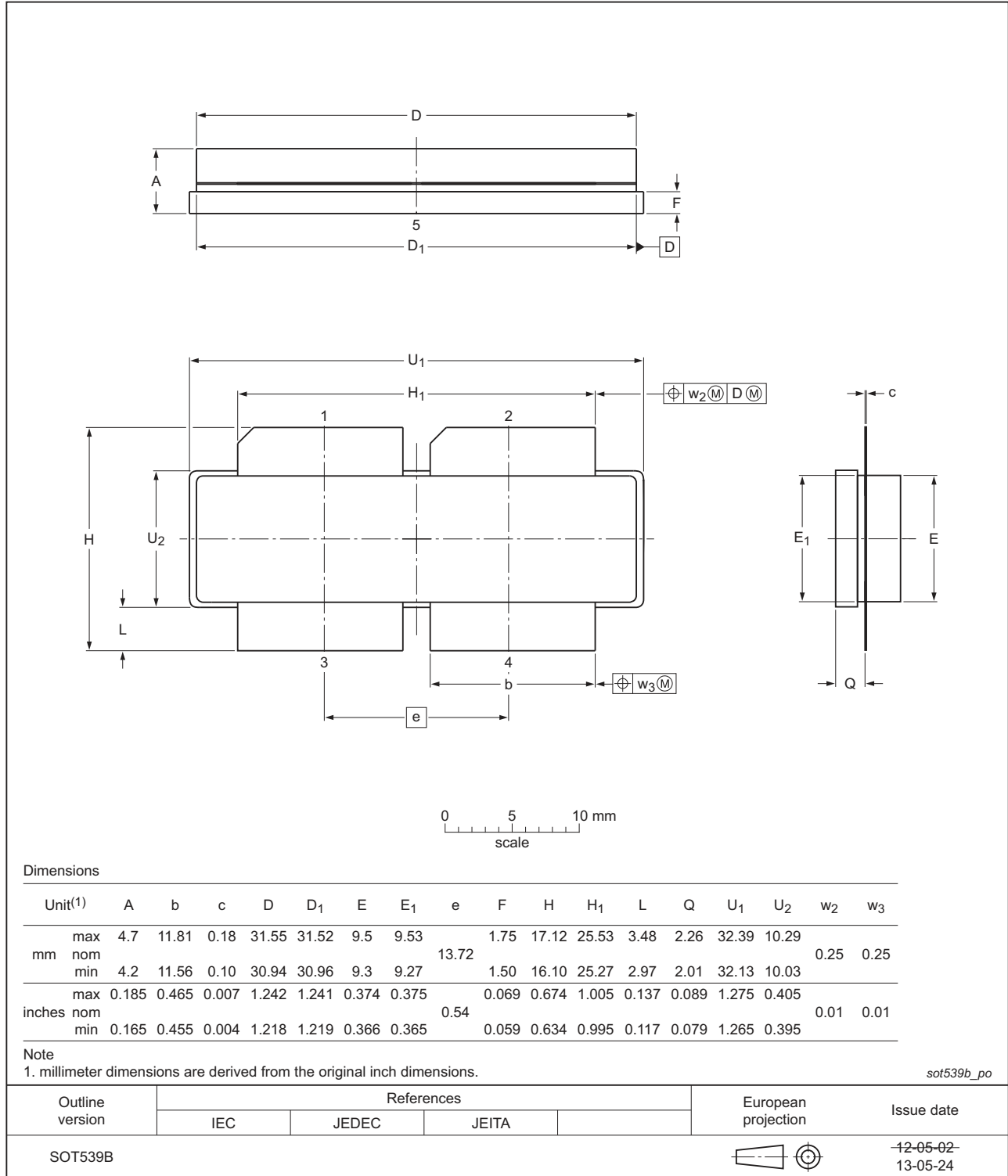



Fig 38. Package outline SOT539B

9. Handling information

CAUTION	
	<p>This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.</p> <p>Such precautions are described in the <i>ANSI/ESD S20.20</i>, <i>IEC/ST 61340-5</i>, <i>JESD625-A</i> or equivalent standards.</p>

10. Abbreviations

Table 10. Abbreviations

Acronym	Description
ESD	ElectroStatic Discharge
L-band	Long wave Band
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
SMD	Surface Mounted Device
VSWR	Voltage Standing-Wave Ratio

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLL6H1214-500_1214LS-500#4	20150901	Product data sheet		BLL6H1214-500_1214LS-500 v.3
Modifications:	<ul style="list-style-type: none"> The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. Legal texts have been adapted to the new company name where appropriate. 			
BLL6H1214-500_1214LS-500 v.3	20130805	Product data sheet	-	BLL6H1214-500 v.2
BLL6H1214-500 v.2	20100401	Product data sheet	-	BLL6H1214-500 v.1
BLL6H1214-500 v.1	20090120	Objective data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.ampleon.com>.

12.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Ampleon does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Ampleon sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Ampleon and its customer, unless Ampleon and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Ampleon product is deemed to offer functions and qualities beyond those described in the Product data sheet.

12.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Ampleon does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Ampleon takes no responsibility for the content in this document if provided by an information source outside of Ampleon.

In no event shall Ampleon be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Ampleon' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of Ampleon.

Right to make changes — Ampleon reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Ampleon products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an

Ampleon product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Ampleon and its suppliers accept no liability for inclusion and/or use of Ampleon products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Ampleon makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Ampleon products, and Ampleon accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Ampleon product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Ampleon does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Ampleon products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Ampleon does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Ampleon products are sold subject to the general terms and conditions of commercial sale, as published at <http://www.ampleon.com/terms>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Ampleon hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Ampleon products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific Ampleon product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Ampleon accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Ampleon' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond Ampleon' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Ampleon for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Ampleon' standard warranty and Ampleon' product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

13. Contact information

For more information, please visit:
<http://www.ampleon.com>

12.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

Any reference or use of any 'NXP' trademark in this document or in or on the surface of Ampleon products does not result in any claim, liability or entitlement vis-à-vis the owner of this trademark. Ampleon is no longer part of the NXP group of companies and any reference to or use of the 'NXP' trademarks will be replaced by reference to or use of Ampleon's own Any reference or use of any 'NXP' trademark in this document or in or on the surface of Ampleon products does not result in any claim, liability or entitlement vis-à-vis the owner of this trademark. Ampleon is no longer part of the NXP group of companies and any reference to or use of the 'NXP' trademarks will be replaced by reference to or use of Ampleon's own trademarks.

For sales office addresses, please visit:
<http://www.ampleon.com/sales>

14. Contents

1 **Product profile** 1

1.1 General description 1

1.2 Features and benefits 1

1.3 Applications 1

2 **Pinning information** 2

3 **Ordering information** 2

4 **Limiting values** 2

5 **Thermal characteristics** 3

6 **Characteristics** 3

7 **Test information** 4

7.1 Ruggedness in class-AB operation 4

7.2 Impedance information 4

7.3 Test circuit 4

7.4 RF performance graphs 6

7.4.1 Performance curves measured with $\delta = 10\%$, $t_p = 300\ \mu\text{s}$ and $T_h = 25\ ^\circ\text{C}$ 6

7.4.2 Performance curves measured with $\delta = 10\%$, $t_p = 300\ \mu\text{s}$ and $T_h = 65\ ^\circ\text{C}$ 7

7.4.3 Performance curves measured with $\delta = 10\%$, $t_p = 300\ \mu\text{s}$ and $f = 1300\ \text{MHz}$ 8

7.4.4 Performance curves measured with $\delta = 20\%$, $t_p = 500\ \mu\text{s}$ and $T_h = 25\ ^\circ\text{C}$ 9

7.4.5 Performance curves measured with $\delta = 20\%$, $t_p = 500\ \mu\text{s}$ and $T_h = 65\ ^\circ\text{C}$ 10

7.4.6 Performance curves measured with $\delta = 20\%$, $t_p = 500\ \mu\text{s}$ and $f = 1300\ \text{MHz}$ 11

7.4.7 Performance curves measured with $\delta = 10\%$, $t_p = 1\ \text{ms}$ and $T_h = 25\ ^\circ\text{C}$ 12

7.4.8 Performance curves measured with $\delta = 10\%$, $t_p = 1\ \text{ms}$ and $T_h = 65\ ^\circ\text{C}$ 13

7.4.9 Performance curves measured with $\delta = 10\%$, $t_p = 1\ \text{ms}$ and $f = 1300\ \text{MHz}$ 14

8 **Package outline** 16

9 **Handling information** 18

10 **Abbreviations** 18

11 **Revision history** 18

12 **Legal information** 19

12.1 Data sheet status 19

12.2 Definitions 19

12.3 Disclaimers 19

12.4 Trademarks 20

13 **Contact information** 20

14 **Contents** 21

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© Ampleon The Netherlands B.V. 2015. All rights reserved.

For more information, please visit: <http://www.ampleon.com>
 For sales office addresses, please visit: <http://www.ampleon.com/sales>

Date of release: 1 September 2015

Document identifier: BLL6H1214-500_1214LS-500#4